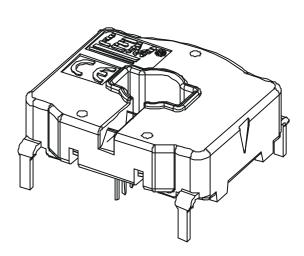
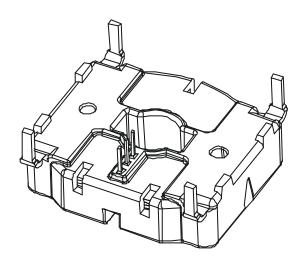


AUTOMOTIVE CURRENT SENSOR HC6F500-S

CE









Introduction

The HC6F Family is for use on the electronic measurement of DC, AC or pulsed currents in high power and low voltage automotive applications with a galvanic isolation between the primary circuit (high power) and the secondary circuit (electronic circuit).

The HC6F family gives you the choice of having different current measuring ranges in the same housing.

Features

- Open Loop transducer using the Hall effect
- Low voltage application
- Unipolar + 5 V DC power supply
- Primary current measuring range from 200 A up to 800 A
- Maximum rms primary admissible current: defined by busbar to have T° < + 150 °C
- Operating temperature range: 40 °C < T° < + 125 °C
- Output voltage: full ratio-metric (in gain and offset)
- Compact design for PCB mounting.

Advantages

- · Excellent accuracy
- · Very good linearity
- · Very low thermal offset drift
- Very low thermal gain drift
- Wide frequency bandwidth
- Noinsertionlosses
- Very good ratio size/current range

Automotive applications

- Starter Generators
- Converters
- Inverters
- Drives.

Principle of HC6F Family

The open loop transducers use an Hall effect integrated circuit. The magnetic induction B, contributing to the rise of the Hall voltage, is generated by the primary current I_p to be measured. The control current I_p is supplied by a current source i.e. battery or generator (Fig. 1).

Within the linear region of the hysteresis cycle, \boldsymbol{B} is proportional to:

$$I_{p}$$
 (B) = constant (a) x I_{p}

The Hall voltage is thus expressed by:

$$V_{\perp} = (K/d) \times I \times constant (a) \times I_{p}$$

Except for I_p , all terms of this equation are constant. Therefore:

$$V_{H}$$
 = constant (b) x I_{P}

The measurement signal \mathbf{V}_{H} amplified to supply the user output voltage or current.

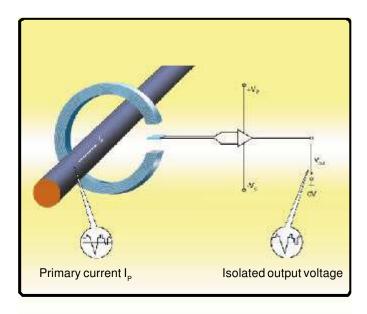


Fig. 1: Principle of the open loop transducer



Dimensions HC6Fxxx-S family (in mm. 1mm = 0.0394 inch)

Secondary connection

| Terminals | Designations |
|-----------|-------------------------|
| 3 | Supply voltage + 5 V DC |
| 1 | V _{out} |
| 2 | Ground |
| E1 to E4 | Ground (*) |

Transducer name:
HE6F500-S
{xxx= Current Range}

Date code

1 Y DDD HHMM
Production contar Year Day Time
1- General

Molding
Date stamp
E4

Cavity number

Plastic material

A (See version table)

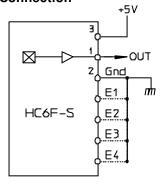
25.4

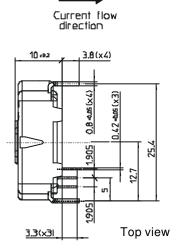
Rear view

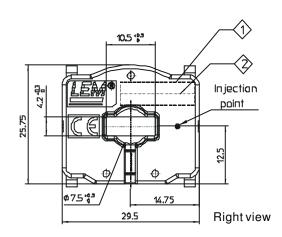
Modification index

(*) Only 1 of these 4 pins could be connected

Connection







Bill of materials

• Plastic case

• Magnetic core

• Pins

Mass

SPS GF 30 FeSi alloy Copper alloy tin platted (lead free)

23 g

Remarks

• General tolerance

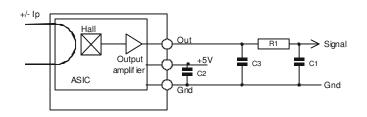
±0.2 mm

: C3 = 4.7 nF

• $V_{\text{OUT}} > \frac{V_c}{2}$ when I_p flows in the direction of the arrow.

Power supply decoupling capacitor: C2 = 47 nF

Electronic schematic



Optional:

High frequency signal noise filter:

EMC protection capacitor

R1 > 100 ohms

C1 = defined according to the system frequency bandwidth



Absolute maximum ratings (not operating)

| Parameter | Symbol | Unit | Specification | Consitions |
|--|----------------------|-------------------|---------------------------------------|---------------|
| Maximun peak primary current (not operating) | P maxi | Α | Defined by busbar to have T°≤ 150 °C | |
| Primary nominal DC or rms current | I _{PN} | Α | Defined by busbar to have T° ≤ 150 °C | |
| Maximun supply voltage (not operating) | \mathbf{V}_{Cmaxi} | V | 7 | |
| Secondary maximum admissible power | P S maxi | mW | 150 | |
| Ambient operating temperature | T _A | ℃ | - 40 < T _A < 125 ℃ | |
| Ambient storage temperature | Ts | ℃ | - 40 < T _S < 125 ℃ | |
| Electrostatic discharge voltage | V _{ESD} | V | 2000 | JESD22-A114-B |
| Maximum admissible vibration | γ | m.s ⁻² | 100 | IEC60068-2-64 |
| Rms voltage for AC isolation test | V_d | V | 2000 | IEC 60664-1 |

Operating characteristics

| | Symbol Unit | l lm!A | Specification | | | Conditions | | | |
|-------------------------------------|-------------------------------------|--------------|----------------------|---|---------|---|--|--|--|
| | | Unit | Mini | Typical | Maxi | Conditions | | | |
| Electrical Data | | | | | | | | | |
| Primary current, measuring range | I _{PM} | Α | -500 | - | 500 | @ - 40℃ < T° < 125℃ | | | |
| Supply voltage 1) | V _C | V | 4.75 | 5.00 | 5.25 | @ - 40℃ < T° < 125℃ | | | |
| Output voltage(Analog) 1) | V out | V | V _{OUT} = V | $V_{OUT} = V_{C}/5 \cdot (2.5 + 0.004 \cdot I)$ | | @ - 40℃ < T° < 125℃ | | | |
| Sensitivity | G | V/A | 0.00392 | 0.004 | 0.00408 | @ T A = 25℃ | | | |
| Offset voltage | V O | V | 2.482 | 2.5 | 2.518 | @ $V_C = 5 \text{ V}$; $T_A = 25 ^{\circ}\text{C}$; $I_P = 0 \text{ A}$ | | | |
| Current consumption | lc | mA | - | 15 | 20 | @ - 40°C < T° < 125°C; 4.75 V < V _C < 5.25 V | | | |
| Load resistance | R∟ | ΚΩ | 2 | - | - | | | | |
| Output internal resistance | R _{OUT} | Ω | - | - | 10 | | | | |
| | Performance Data | | | | | | | | |
| Sensitivity error 1) | € G | % | -2.0 | ±0.7 | 2.0 | @ T A = 25 °C, V C = 5V; Gth = 0.004 V/A | | | |
| Electrical offset current | I _{OE} | Α | -2.5 | ±1.1 | 2.5 | @ V _C = 5 V; T _A = 25 ℃ | | | |
| Liectrical offset current | V OE | mV | -10 | ±4.4 | 10 | W VC = 5 V, TA = 25 C | | | |
| Magnetic offset current | Іом | Α | -2.5 | ±1.5 | 2.5 | | | | |
| inagnotic chock carroin | Vом | mV | -10 | ±6 | 10 | G / Hor oxedicion to Ell , 1x = 20 0 | | | |
| Temperature coefficient of | TCI _{OE} | mA/℃ | -35 | ±15 | 35 | @ - 40°C < T° < 125°C; V _C = 5 V | | | |
| | TCV OE | mV/℃ | -0.14 | ±0.06 | 0.14 | C 10 0 1 1 1 1 2 0, 10 0 1 | | | |
| Temperature coefficient of G | TCG | %/℃ | -0.04 | ±0.02 | 0.04 | @ - 40 °C < T° < 125 °C; V _C = 5 V | | | |
| Linearity error | $\epsilon_{\!\scriptscriptstyle L}$ | % I P | -1.0 | ±0.5 | 1.0 | @ I _P ; V _C = 5.00 V, T _A = 25 ℃ | | | |
| Response time | t r | μs | - | 8 | 15 | @ di/dt = 50 A/µs; I _T = 400 A | | | |
| Frequency bandwidth 2) | BW | kHz | 20 | - | - | @ -3 dB | | | |
| Output voltage noise peak-peak | V no p-p | mV | - | 8 | 12 | @ T A = 25 °C; 0 Hz < f < 1 MHz | | | |
| Output voltage noise rms | V no rms | mV | - | 2.5 | 3.5 | @ T A = 25 °C; 0 Hz < f < 1 MHz | | | |

Notes: 1) The output voltage \mathbf{V}_{OUT} is fully ratio-metric and depends on the supply voltage \mathbf{V}_{C} . The \mathbf{V}_{C} value must be measured and used with the following formula:

$$Ip = \left(Vout - \frac{Vc}{2}\right) \times \frac{1}{G} \times \frac{5}{Vc} \qquad With G in (V/A)$$

 $^{\rm 2)}$ Small signal only to avoid excessive heatings of the magnetic core.



PERFORMANCE PARAMETERS DEFINITIONS

Sensitivity:

The Transducer's sensitivity ${\bf G}$ is the slope of the straight line ${\bf V}_{\rm out}$ = f (${\bf I}_{\rm p}$), it must establish the relation:

$$V_{out}(I_p) = V_c/5 (G \times I_p + 2.5) (*)$$

* For all symetrics transducers

Offset voltage:

Is the output voltage when the primary current is null. The ideal value of \mathbf{V}_{\odot} is $\mathbf{V}_{\rm c}/2$. So, the difference of \mathbf{V}_{\odot} - $\mathbf{V}_{\rm c}/2$ is called the total offset voltage error. This offset error can be attributed to the electrical offset (due to the resolution of the ASIC quiescent voltage trimming), the magnetic offset, the thermal drift and the thermal hysteresis.

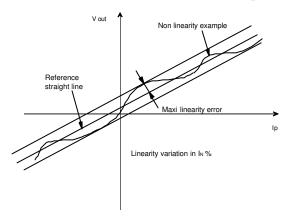
Magnetic offset:

The magnetic offset is the consequence of an over-current on the primary side. It's defined after an excursion of $\mathbf{I}_{P \text{ max}i}$.

Linearity:

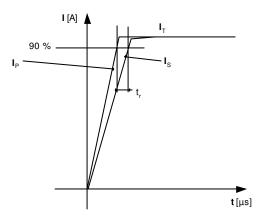
Is the maximum positive or negative discrepancy with a reference straight line $\mathbf{V}_{\text{OUT}} = \mathbf{f}(\mathbf{I}_{\text{p}})$.

Unit: linearity (%) expressed with full scale of $I_{P \text{ maxi}}$.



Response time (delay time) t:

Is the time between the primary current signal and the output signal reach at 90 % of its final value



Output noise voltage:

The output voltage noise is the result of the noise floor of the Hall elements and the linear I_c amplifier sensitivity.

Offset drift:

The error of the offset in the operating temperature \mathcal{E} Offset is the relative variation of the offset in the temperature considered with the initial offset at 25 °C. The offset temperature coefficient TCV_{OE} (TCI_{OE}) in the operating temperature is the slope off \mathcal{E} Offset = \mathbf{f} (T).

Sensitivity drift:

The error of the sensitivity in the operating temperature Sensitivity Error is the relative variation of the sensitivity in the temperature considered with the initial sensitivity at 25 °C. Sensitivity temperature coefficient TCE $_{\rm c}$.

Typical:

Theorical value or usual accuracy recorded during the production.

Environmental test specifications

| Name | Standard | Conditions | | | | | |
|---|---------------------|--|--|--|--|--|--|
| Thermal shocks | IEC 60068 Part 2-14 | T° - 40 °C to 125 °C /1000 cycles not connected | | | | | |
| Low Toperation at mini supply voltage | IEC 60068 Part 2-1 | T° - 40 °C / 1000 H supply voltage = 4.75 V | | | | | |
| High T° operation at maxi supply voltage | IEC 60068 Part 2-2 | T° 125 °C / 1000 H supply voltage = 5.25 V | | | | | |
| Temperature humidity bias | IEC 60068 Part 2-3 | T°85℃ / 85 % RH/1000 H | | | | | |
| Mechanical Tests | | | | | | | |
| Vibration | IEC 60068 Part 2-64 | see note (2) page 4 | | | | | |
| Drop test | IEC 60068 Part 2-29 | Height 750 mm concrete floor each directions | | | | | |
| EMC Test | | | | | | | |
| Electrostatic discharge | JESD22-A114-B | Applied voltage = \pm 2 kV pin to pin number of discharge = 1 | | | | | |
| Rms voltage for AC isolation test | IEC 60664 Part 1 | 2 kV, 50 Hz, 1 min | | | | | |
| Bulk current injected- radiated immunity | ISO 11452 Part 4 | | | | | | |